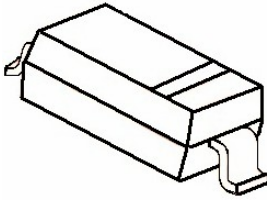


**SOD-123**

**Features**

- Low Zener Impedance
- Power Dissipation of 500mW
- High Stability and High Reliability

**Mechanical Data**

- SOD-123 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- EpoxyUL:94V-0
- Mounting Position: Any

**Maximum Ratings & Thermal Characteristics**

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameters	Symbol	Value	Unit
Power Dissipation	Pd	500 <sup>1)</sup>	mW
Forward Voltage @IF=10mA	Vf	0.9 <sup>2)</sup>	V
Storage temperature range	Ts	-65-+150	°C

 1) Device mounted on ceramic PCB: 7.6mm x 9.4mm x 0.87mm with pad areas 25mm<sup>2</sup>

2) Short duration test pulse used to minimize self-heating effect

3) f=1KHz

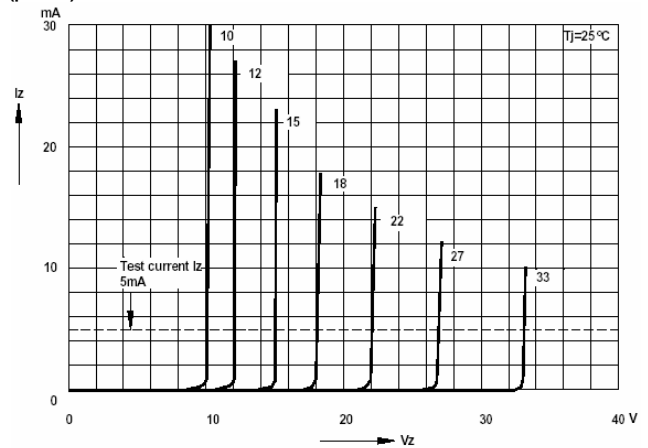
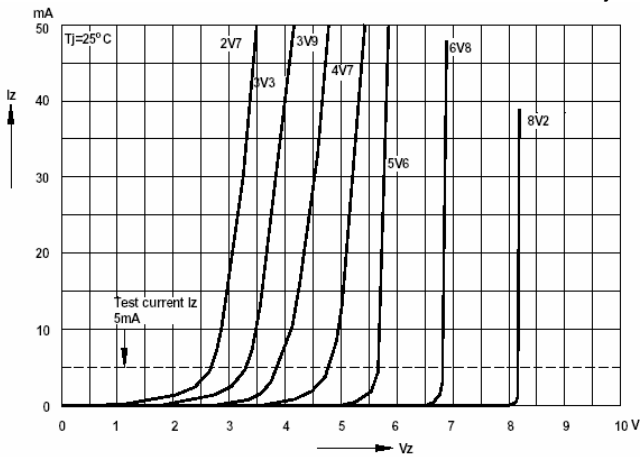
**Electrical Characteristics**

(Ratings at 25°C ambient temperature unless otherwise specified.)

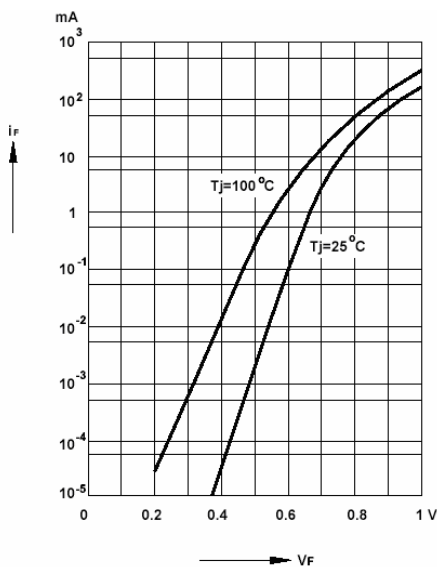
Device	Marking	Zener Voltage Range				Maximum Zener Impedance			Maximum Reverse Current		Typical Temperature coefficient @ IZTC=mV/°C		Test Current IZTC
		Vz@Izt			Izt	Zzt @Izt	Zzk @Izk	Izk	IR	VR	Min	Max	
		Nom(V)	Min(V)	Max(V)									
BZT52C2V4	WX	2.4	2.2	2.6	5	100	600	1.0	50	1.0	-3.5	0	5
BZT52C2V7	W1	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0	5
BZT52C3V0	W2	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0	5
BZT52C3V3	W3	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0	5
BZT52C3V6	W4	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0	5
BZT52C3V9	W5	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V3	W6	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0	5
BZT52C4V7	W7	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2	5
BZT52C5V1	W8	5.1	4.8	5.4	5	60	480	1.0	2	2.0	-2.7	1.2	5
BZT52C5V6	W9	5.6	5.2	6.0	5	40	400	1.0	1	2.0	-2.0	2.5	5
BZT52C6V2	WA	6.2	5.8	6.6	5	10	150	1.0	3	4.0	0.4	3.7	5
BZT52C6V8	WB	6.8	6.4	7.2	5	15	80	1.0	2	4.0	1.2	4.5	5
BZT52C7V5	WC	7.5	7.0	7.9	5	15	80	1.0	1	5.0	2.5	5.3	5
BZT52C8V2	WD	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2	5
BZT52C9V1	WE	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0	5
BZT52C10	WF	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0	5
BZT52C11	WG	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0	5
BZT52C12	WH	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0	5
BZT52C13	WI	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0	5

Device	Marking	Zener Voltage Range				Maximum Zener Impedance			Maximum Reverse Current		Typical Temperature coefficient @ IZTC=mV/°C		Test Current IZTC
		Vz@Izt			Izt	Zzt @Izt	Zzk @Izk	Izk	IR	VR	Min	Max	
		Nom(V)	Min(V)	Max(V)									
BZT52C15	WJ	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13.0	5
BZT52C16	WK	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14.0	5
BZT52C18	WL	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16.0	5
BZT52C20	WM	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0	5
BZT52C22	WN	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0	5
BZT52C24	WO	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0	5
BZT52C27	WP	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3	2
BZT52C30	WQ	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4	2
BZT52C33	WR	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4	2
BZT52C36	WS	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4	2
BZT52C39	WT	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2	2
BZT52C43	WU	43	40.0	46.0	2	100	700	1.0	0.1	32.0	10.0	12.0	5
BZT52C47	WV	47	44.0	50.0	2	100	750	1.0	0.1	35.0	10.0	12.0	5
BZT52C51	WW	51	48.0	54.0	2	100	750	1.0	0.1	38.0	10.0	12.0	5

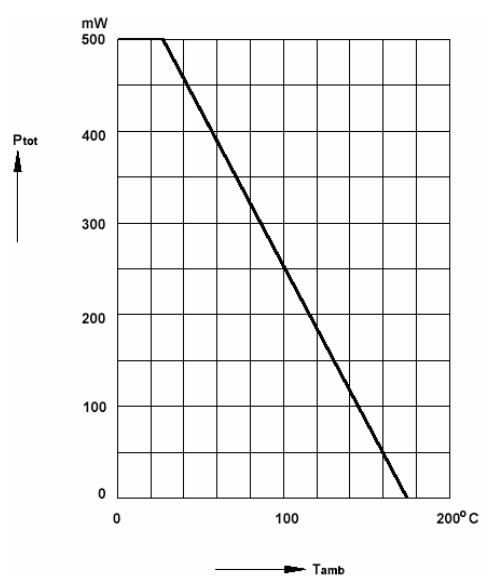
at Tj=constant (pulsed)



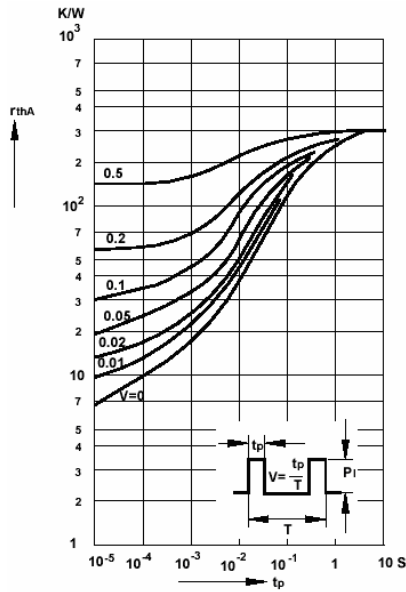
Forward characteristics



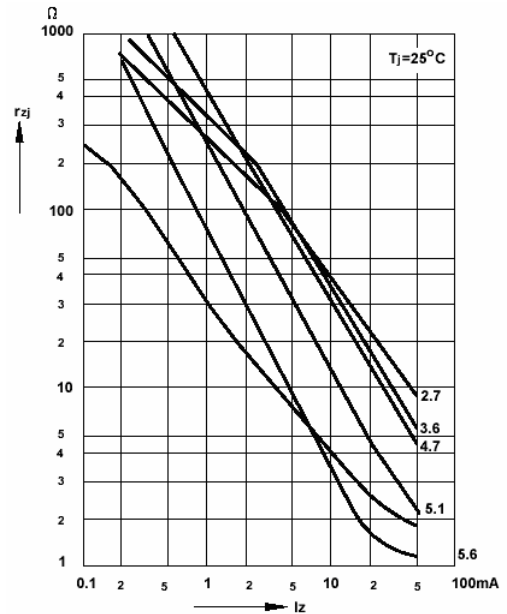
Admissible power dissipation versus ambient temperature



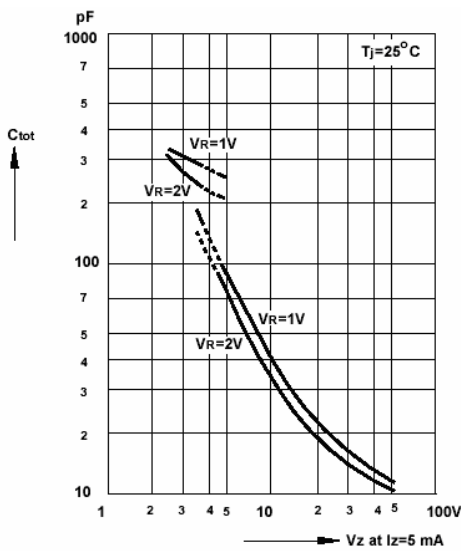
**Pulse thermal resistance versus pulse duration**



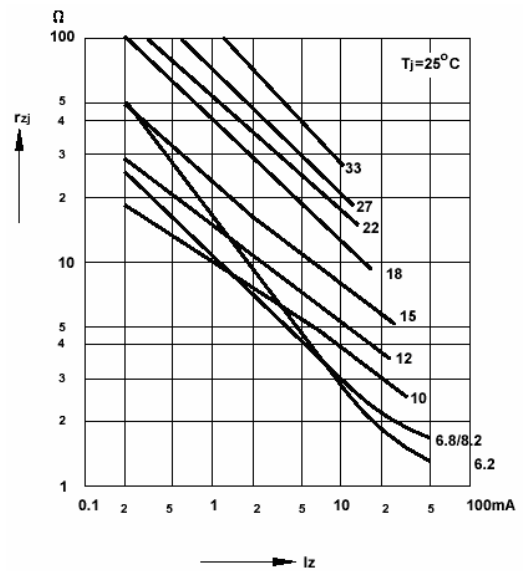
**Dynamic resistance versus Zener current**



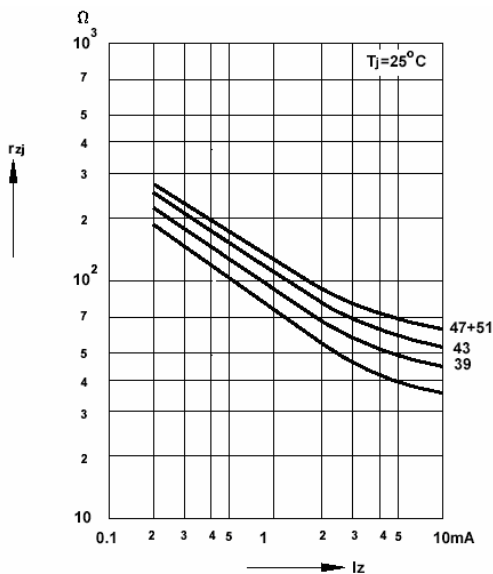
**Capacitance versus Zener voltage**



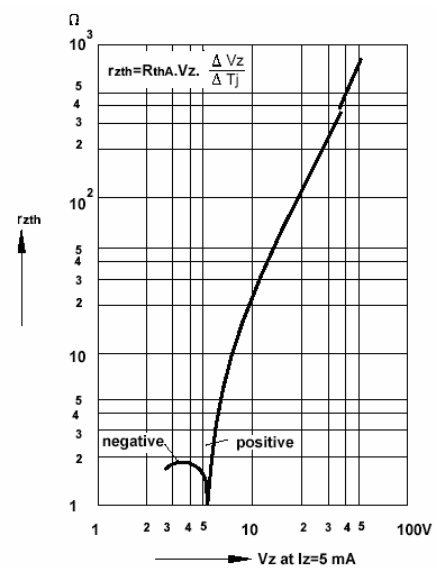
**Dynamic resistance versus Zener current**



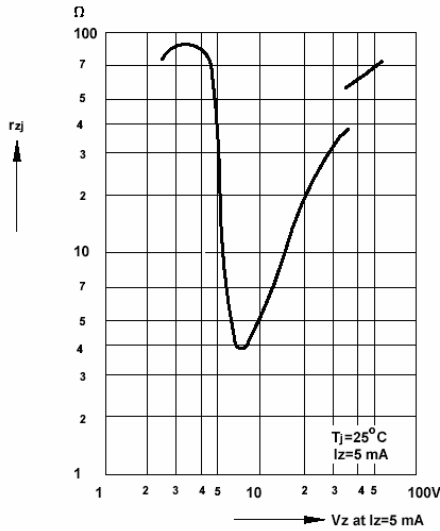
**Dynamic resistance versus Zener current**



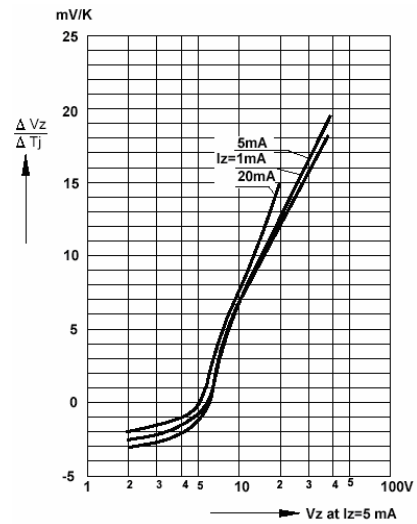
**Thermal differential resistance versus Zener voltage**



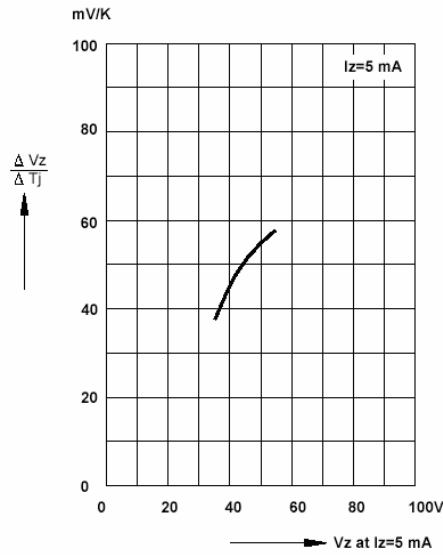
**Dynamic resistance versus Zener voltage**



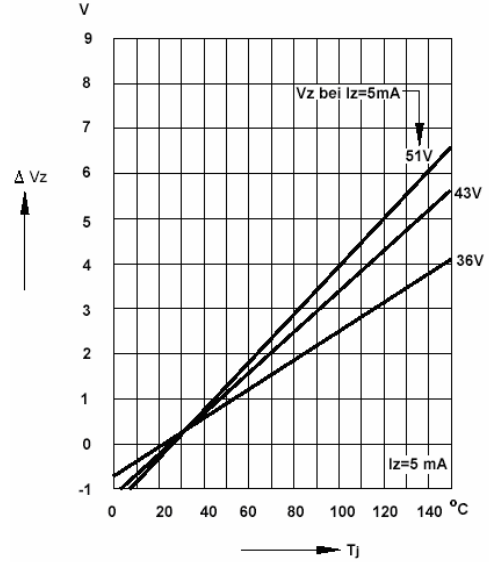
**Temperature dependence of Zener voltage versus Zener voltage**



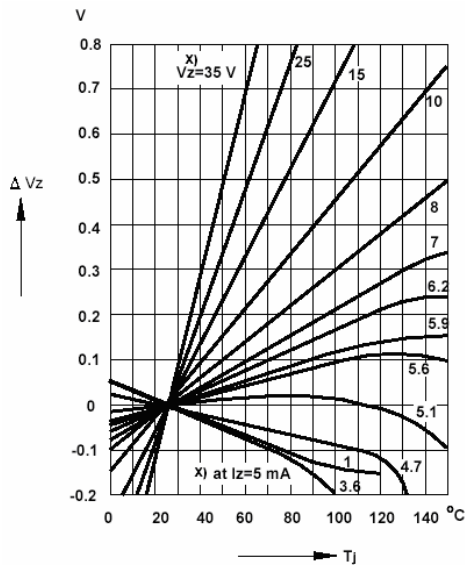
**Temperature dependence of Zener voltage versus Zener voltage**



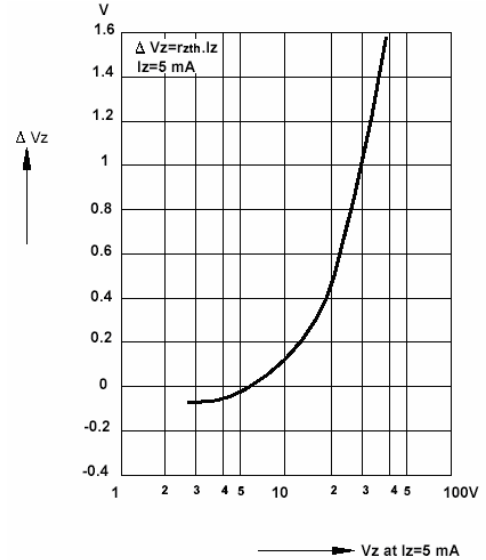
**Change of Zener voltage versus junction temperature**

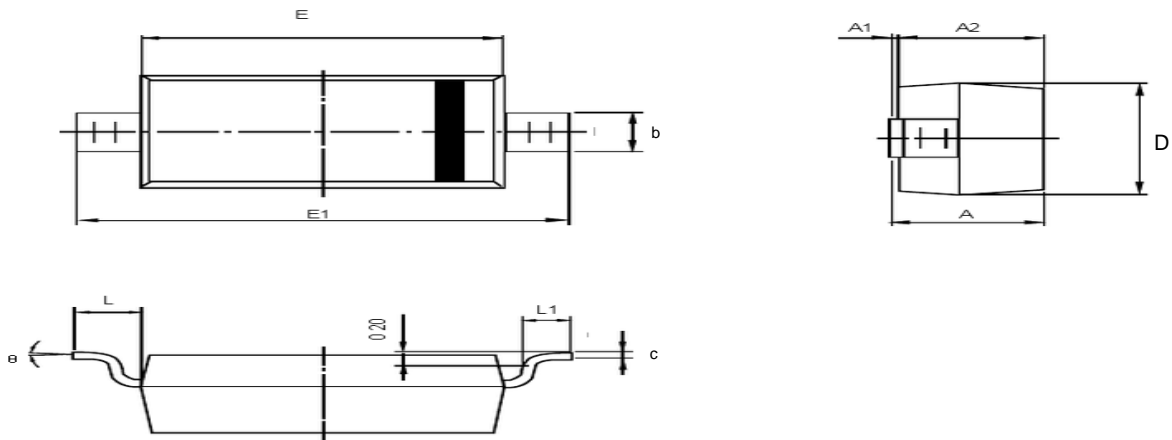


**Change of Zener voltage versus junction temperature**



**Change of Zener voltage from turn-on up to the point of thermal equilibrium versus Zener voltage**



**SOD-123 PACKAGE OUTLINE** Plastic surface mounted package


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
c	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500REF		0.020REF	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Zener Diodes](#) category:*

*Click to view products by [Bourne](#) manufacturer:*

Other Similar products are found below :

[RKZ13B2KG#P1](#) [DL5234B](#) [EDZTE6113B](#) [1N4682](#) [1N4691](#) [1N4693](#) [1N4732A](#) [1N4736A](#) [1N4750A](#) [1N4759ARL](#) [1N5241B](#) [1N5365B](#)  
[1N5369B](#) [1N747A](#) [1N959B](#) [1N964B](#) [1N966B](#) [1N968B](#) [1N972B](#) [NTE5121A](#) [NTE5147A](#) [NTE5152A](#) [NTE5155A](#) [NTE5164A](#)  
[JANS1N4974US](#) [1N4692](#) [1N4700](#) [1N4702](#) [1N4704](#) [1N4711](#) [1N4714](#) [1N4737A](#) [1N4745ARL](#) [1N4752A](#) [1N4752ARL](#) [1N4760ARL](#)  
[1N5221B](#) [1N5236B](#) [1N5241BTR](#) [1N5242BTR](#) [1N5350B](#) [1N5352B](#) [1N961BRR1](#) [1N964BRL](#) [RKZ5.1BKU#P6](#) [3SMAJ5946B-TP](#)  
[3SMAJ5950B-TP](#) [3SMBJ5925B-TP](#) [441774C](#) [BZX84C3V9](#)